中电国基南方集团有限公司

WS4A005120A

Silicon Carbide Schottky Diode

G4 MPS Technology

V_{RRM}	=	1200	V
I_F (T_C≤130℃)	=	5	A
Q_C	=	25	nC

Features

- New Thin Wafer Technology
- Low Forward Voltage Drop (V_F)
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V_F
- Temperature-independent Switching

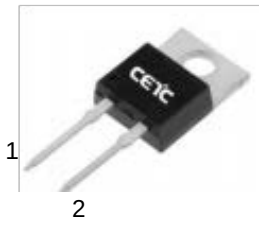
Benefits

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

Applications

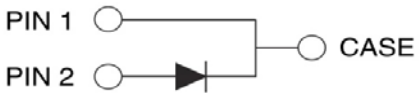
- Switch Mode Power Supplies
- Uninterruptible Power Supplies
- Motor drive, PV Inverter, Wind Power Station

Package



TO-220-2

RoHS



Part Number	Package	Marking
WS4A005120A	TO-220-2	WS4A005120A

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	1200	V	T_C = 25℃	
V_{RSM}	Surge Peak Reverse Voltage	1200	V	T_C = 25℃	
V_R	DC Blocking Voltage	1200	V	T_C = 25℃	
I_F	Forward Current	18 8.75 5	A	TC ≤ 25℃ T_C ≤ 135℃ T_C ≤ 160℃	
I_{FSM}	Non-Repetitive Forward Surge Current	50	A	T_C = 25℃, t_p = 8.3ms, Half Sine Wave	
P_{tot}	Power Dissipation	111	W	T_C = 25℃	Fig.3
T_J, T_{STG}	Operating Junction and Storage Temperature	-55 to 175	℃		
T_{sold}	Soldering Temperature	260	℃		

Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_F	Forward Voltage	1.45 2.0	1.8 2.3	V	I_F = 5A, T_J = 25℃ I_F = 5A, T_J = 175℃	Fig.1
I_R	Reverse Current	4 25	50 400	μA	V_R = 1200V, T_J = 25℃ V_R = 1200V, T_J = 175℃	Fig.2
C	Total Capacitance	360 26 21	/	pF	V_R = 0.1V, T_J = 25℃, f = 1MHz V_R = 200V, T_J = 25℃, f = 1MHz V_R =400V, T_J = 25℃, f = 1MHz	Fig.5
Q_C	Total Capacitive Charge	25	/	nC	V_R = 400V, I_F = 6A di/dt = 200A/μs, T_J = 25℃	Fig.4

Thermal Characteristics

Symbol	Parameter	Typ.	Unit	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	1.35	℃/W	Fig.6
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	80	℃/W	

Typical Performance

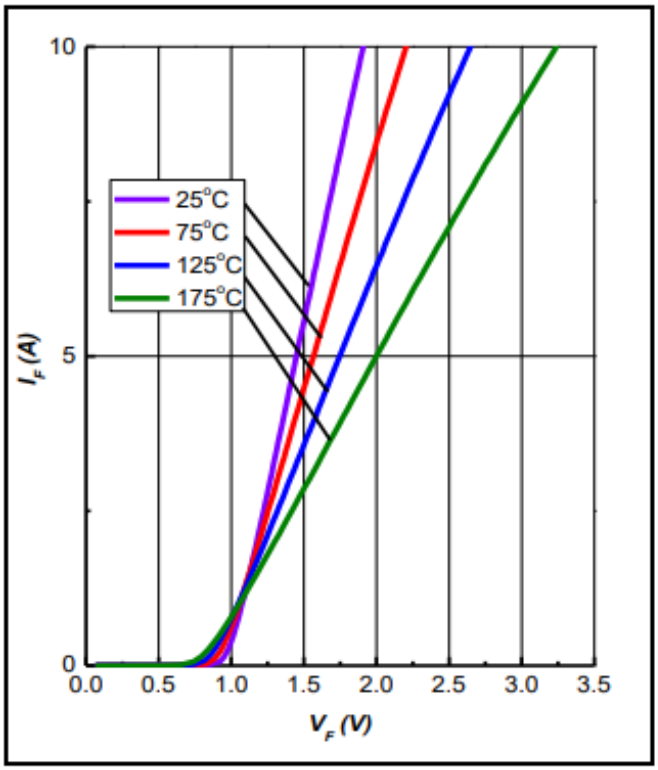


Figure 1. Forward Characteristics

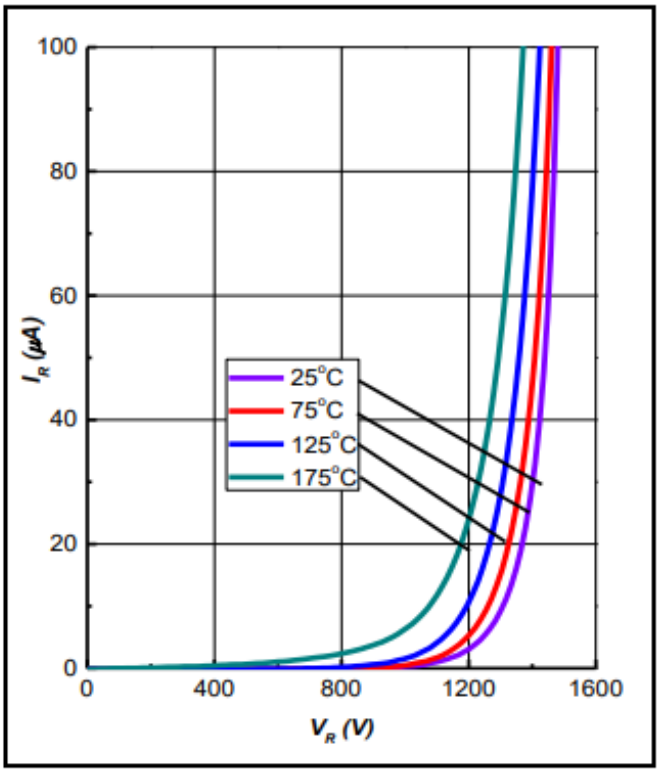


Figure 2. Reverse Characteristics

Typical Performance

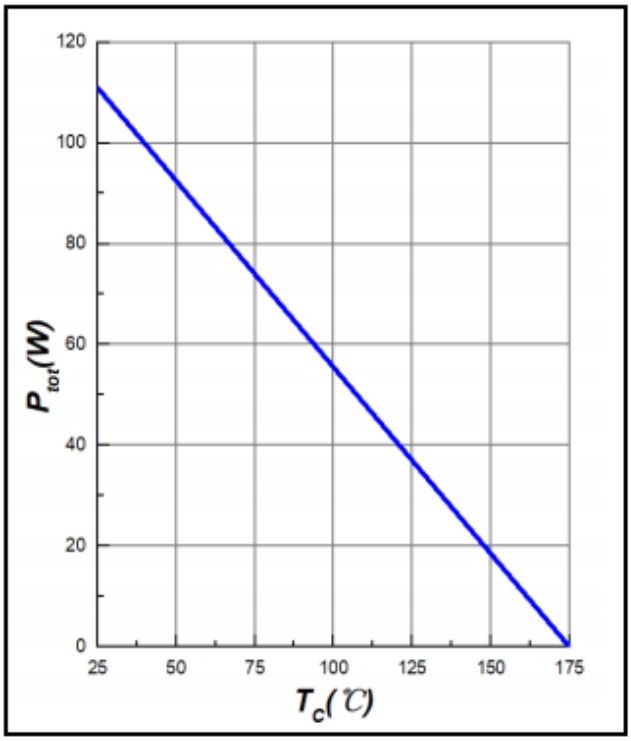


Figure 3. Power Derating

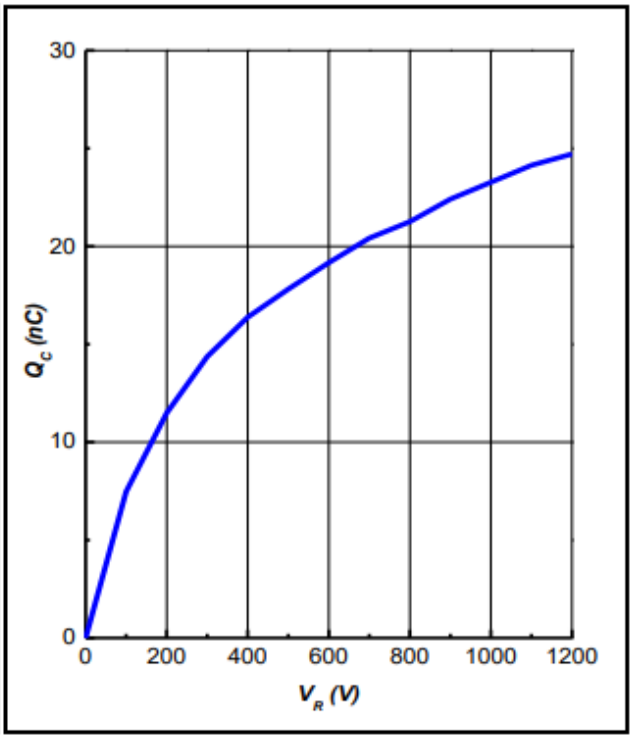
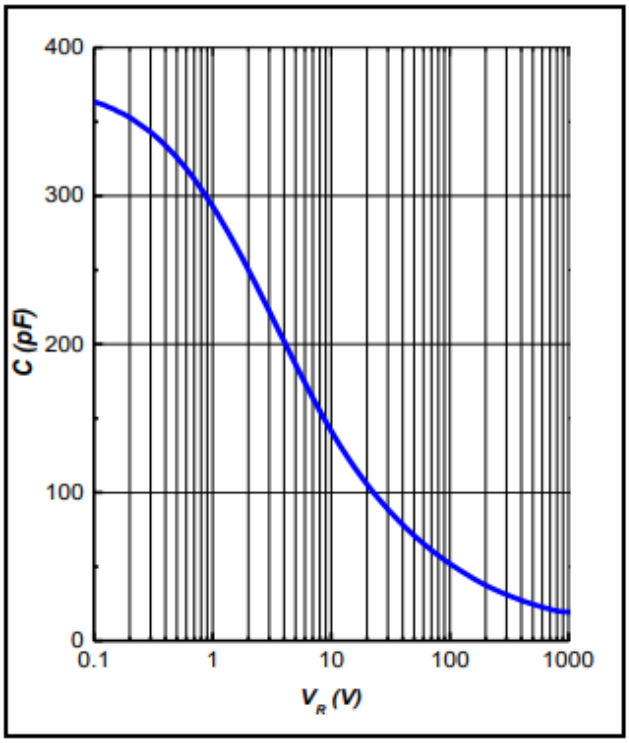


Figure 4. Total Capacitive Charge vs. Reverse Voltage



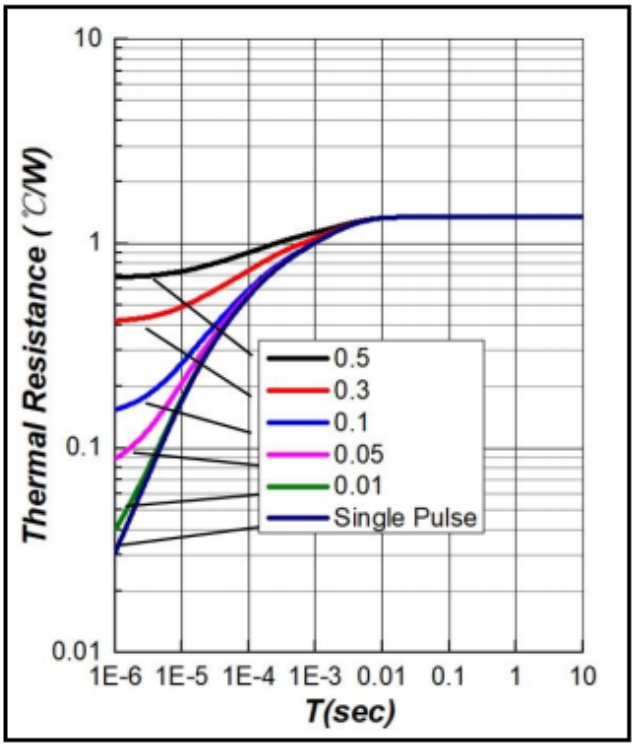
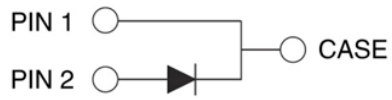


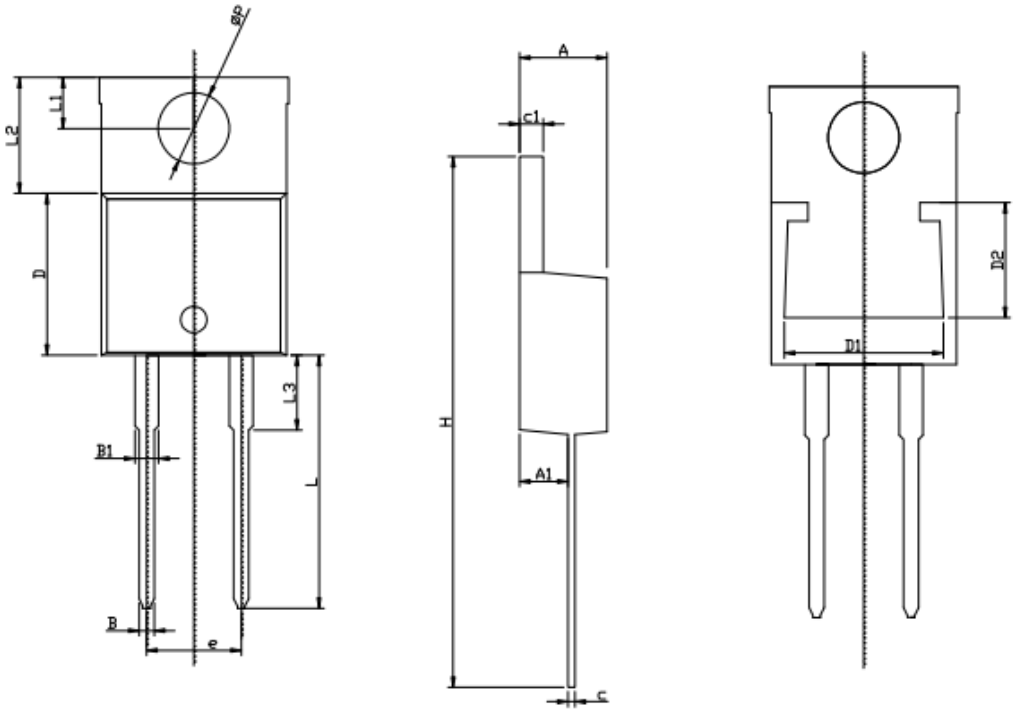
Figure 5. Total Capacitance vs. Reverse Voltage

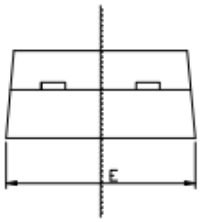
Figure 6. Transient Thermal Impedance

Package Dimensions

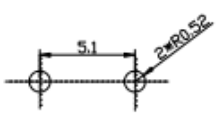
Package TO-220-2







RECOMMENDED LAND PATTERN

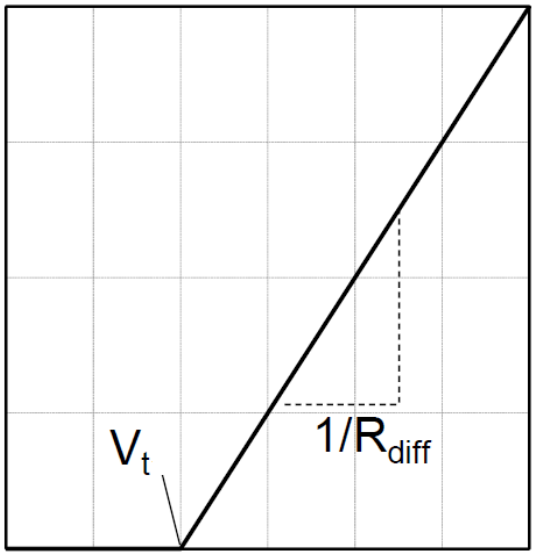


UNIT: mm

	MIN	NOM	MAX
A	4.50	4.70	4.90
A1	2.45	2.60	2.70
B	0.72	0.82	0.92
B1	1.12	1.27	1.42
c	0.28	0.38	0.48
c1	1.17	1.27	1.37
D	8.46	8.66	8.86
D1	7.70	7.90	8.40
D2	5.00	5.20	5.40
e		5.10	
E	9.85	10.15	10.45
H	28.00	28.50	29.00
ΦP		3.84	
L	13.1	13.6	14.1
L1	2.54	2.74	2.94
L2	6.04	6.24	6.44
L3	3.85	4.05	4.35

Simplified Diode Model

Equivalent IV Curve for Model



Mathematical Equation

$$V_F = V_t + I_F \times R_{diff}$$

$V_t = -0.00093 \times T_j + 0.94[V]$

$R_{diff} = 3.4 \times 10^{-6} \times T_j^2 + 4.9 \times 10^{-4} \times T_j + 0.1025[\Omega]$

Note:

Tj = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

I_F= Forward Current

Less than 20A

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